Complementary Silicon Plastic Power Transistors

These devices are designed for use in general–purpose amplifier and switching applications.

Features

- High DC Current Gain
- High Current Gain Bandwidth Product
- TO-220 Compact Package
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS (Note 1)

Rating	Symbol	Value	Unit
Collector–Emitter Voltage 2N6487, 2N6490 2N6488, 2N6491	V _{CEO}	60 80	Vdc
Collector–Base Voltage 2N6487, 2N6490 2N6488, 2N6491	V _{CB}	70 90	Vdc
Emitter-Base Voltage	V _{EB}	5.0	Vdc
Collector Current – Continuous	I _C	15	Adc
Base Current	I _B	5.0	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	75 0.6	W W/°C
Total Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	1.8 0.014	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Indicates JEDEC Registered Data.

THERMAL CHARACTERISTICS

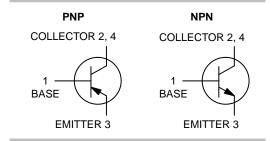
Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.67	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	70	°C/W



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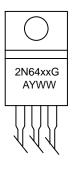
http://onsemi.com

15 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 60-80 VOLTS, 75 WATTS





MARKING DIAGRAM



2N64xx = Specific Device Code xx = See Table on Page 5 G = Pb-Free Package A = Assembly Location

Y = Year WW = Work Week

ORDERING INFORMATION

See detailed ordering, marking, and shipping information in the package dimensions section on page 5 of this data sheet.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted) (Note 2)

Symbol	Min	Max	Unit
V _{CEO(sus)}	60 80	<u>-</u>	Vdc
V _{CEX}	70 90	- -	Vdc
I _{CEO}	-	1.0	mAdc
I _{CEX}	- - -	500 500 5.0 5.0	μAdc
I _{EBO}	-	1.0	mAdc
			•
h _{FE}	20 5.0	150 -	_
V _{CE(sat)}	- -	1.3 3.5	Vdc
V _{BE(on)}		1.3 3.5	Vdc
			•
f _T	5.0	-	MHz
h _{fe}	25	-	-
	VCEO(sus) VCEX ICEO ICEO VCEX IFE VCE(sat) VBE(on)	VCEO(sus) 60 80 70 90 1 1 1 1 1 1 1 1 1	VCEO(sus)

^{2.} Indicates JEDEC Registered Data. 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%. 4. $f_T = |h_{fe}| \bullet f_{test}$

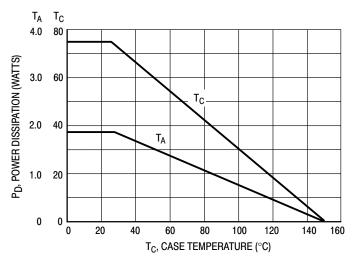
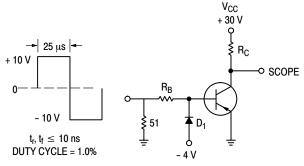


Figure 1. Power Derating

1000



 $\rm R_B$ and $\rm R_C$ varied to obtain desired current levels. For PNP, reverse all polarities.

D₁ MUST BE FAST RECOVERY TYPE, e.g.: 1N5825 USED ABOVE I_B \approx 100 mA MSD6100 USED BELOW I_B \approx 100 mA

500 200 t, TIME (ns) 100 $t_{d} \mathbin{@} V_{BE(off)} \approx 5.0 \ V$ 50 $T_C = 25^{\circ}C$ 20 $V_{CC} = 30 \text{ V}$ $I_C/I_B = 10$ 10 .2 0.5 1.0 2.0 20 IC, COLLECTOR CURRENT (AMP)

Figure 2. Switching Time Test Circuit

Figure 3. Turn-On Time

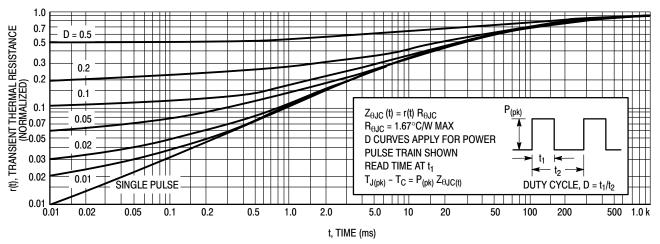


Figure 4. Thermal Response

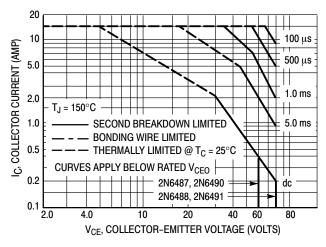


Figure 5. Active-Region Safe Operating Area

There are two limitations on the power handling ability of a transistors average junction temperature and second breakdown. Safe operating area curves indicate I_C-V_{CE} limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)} = 150^{\circ}\text{C}$; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^{\circ}\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

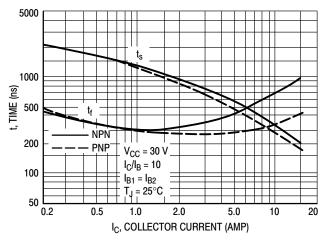


Figure 6. Turn-Off Time

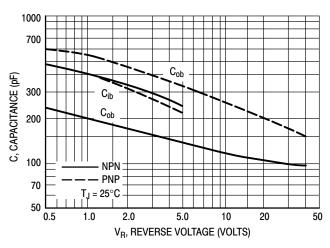
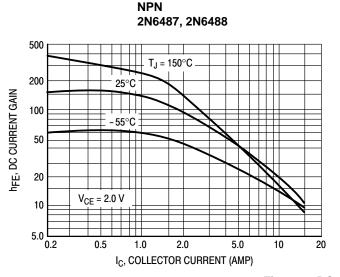


Figure 7. Capacitances



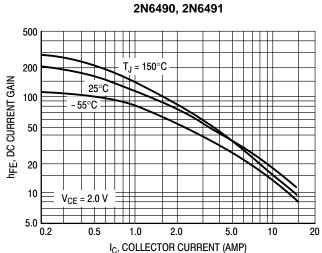


Figure 8. DC Current Gain

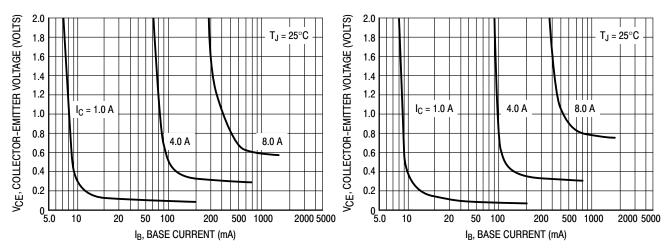


Figure 9. Collector Saturation Region

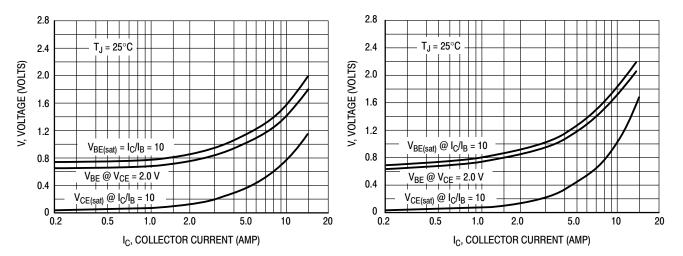


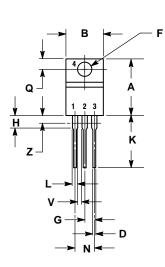
Figure 10. "On" Voltages

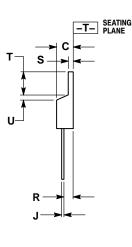
ORDERING INFORMATION

Device	Device Marking	Package	Shipping
2N6487G	2N6487	TO-220 (Pb-Free)	50 Units / Rail
2N6488G	2N6488	TO-220 (Pb-Free)	50 Units / Rail
2N6490G	2N6490	TO-220 (Pb-Free)	50 Units / Rail
2N6491G	2N6491	TO-220 (Pb-Free)	50 Units / Rail

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AG**





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.036	0.64	0.91
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.161	2.80	4.10
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

PIN 1. BASE

- COLLECTOR
- **EMITTER** COLLECTOR

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